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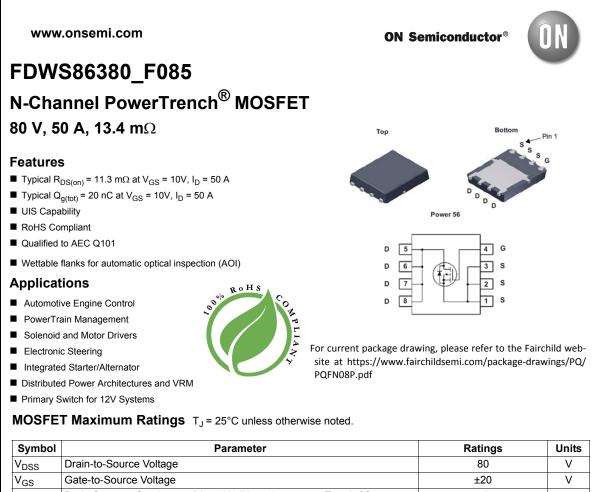


# **ON Semiconductor**®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="https://www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="https://www.onsemi.com">Fairchild\_questions@onsemi.com</a>.

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Symbol	Parameter	Ratings	Units	
V <sub>DSS</sub>	Drain-to-Source Voltage		80	V
V <sub>GS</sub>	Gate-to-Source Voltage		±20	V
	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	$T_C = 25^{\circ}C$	50	^
D	Pulsed Drain Current	T <sub>C</sub> = 25°C	See Figure 4	Α
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	16	mJ
P <sub>D</sub>	Power Dissipation		75	W
	Derate Above 25°C		0.5	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case		2	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W

Notes:

1: Current is limited by bondwire configuration.

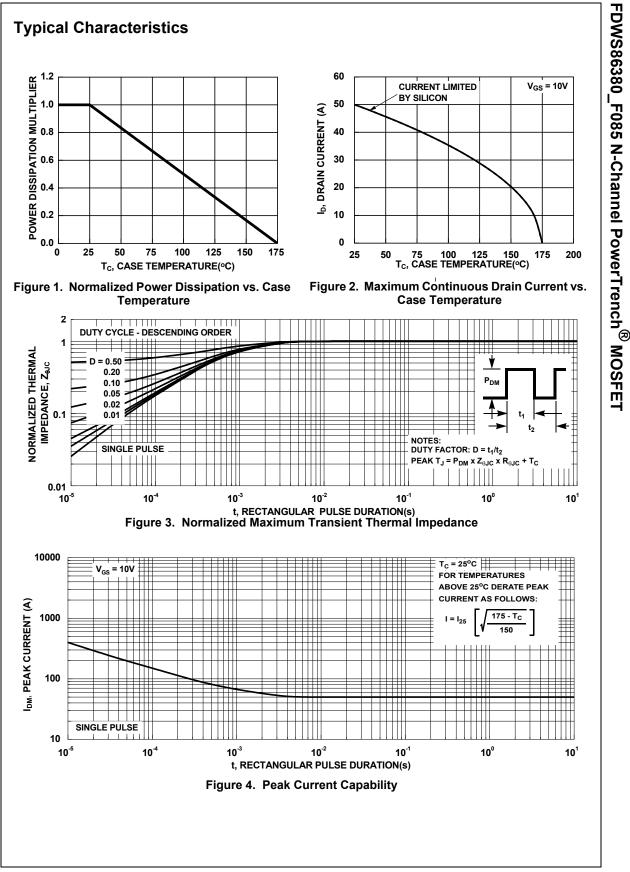
2: Starting T<sub>J</sub> = 25°C, L = 20uH, I<sub>AS</sub> = 40A, V<sub>DD</sub> = 80V during inductor charging and V<sub>DD</sub> = 0V during time in avalanche. 3: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder may the solution of the junction. The maximum ratios  $R_{0,J,A}$  is the sum of the function recrease and ease to emperatively design, while  $R_{0,J,A}$  is determined by the board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

## Package Marking and Ordering Information

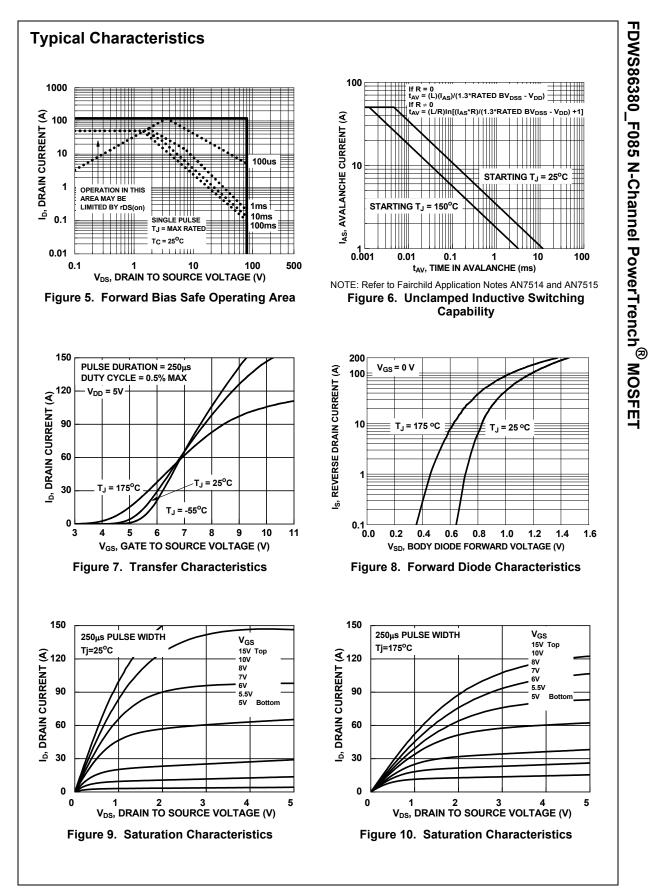
<b>Device Marking</b>	Device	Package	Reel Size	Tape Width	Quantity
FDWS86380	FDWS86380_F085	Power56	13"	12mm	3000units

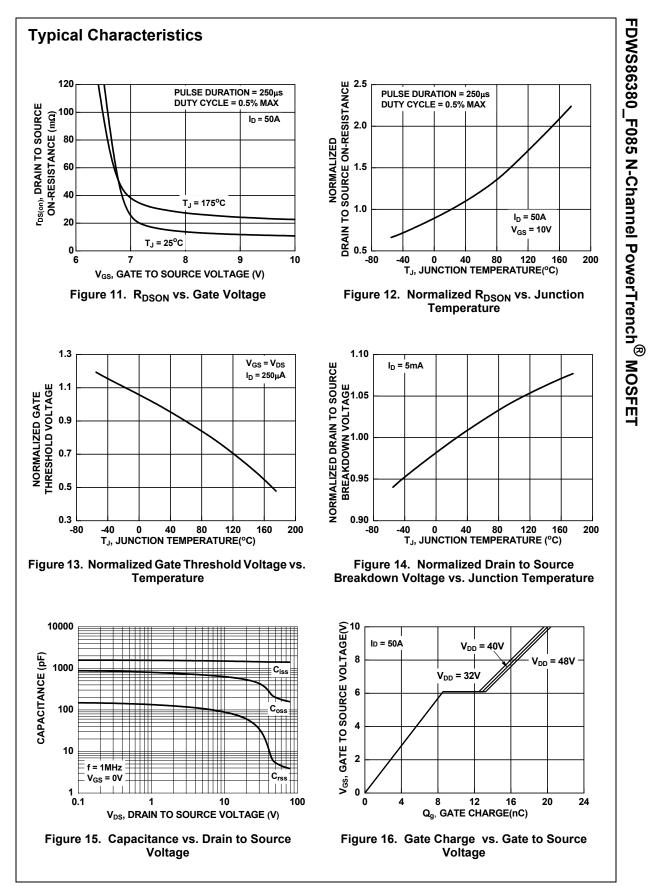
FDWS86380\_F085 N-Channel PowerTrench<sup>®</sup> MOSFET

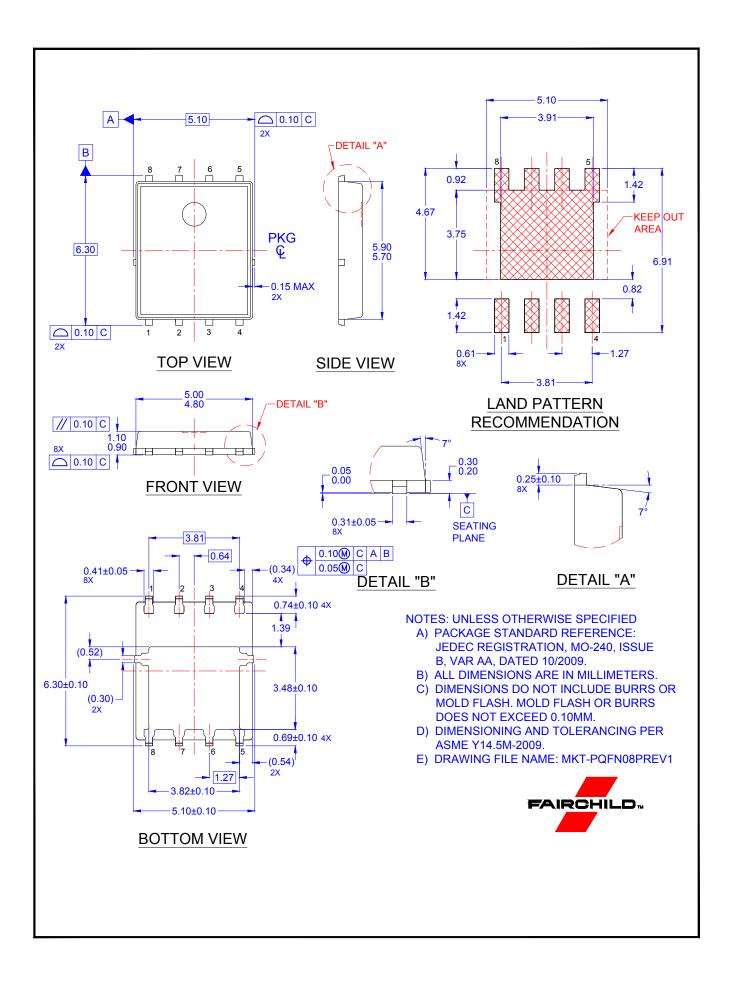
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B <sub>VDSS</sub>	Drain-to-Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V		80	-	-	V
I <sub>DSS</sub>	Drain-to-Source Leakage Current	V <sub>DS</sub> =80V,		-	-	1	μA
		$V_{GS} = 0V$	$T_{\rm J} = 175^{\rm o}C$ (Note 4)	-	-	1	mA
I <sub>GSS</sub>	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Cha	racteristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	V <sub>GS</sub> = V <sub>DS</sub> ,	I <sub>D</sub> = 250μA	2.0	3.0	4.0	V
	Drain to Source On Desistance	I <sub>D</sub> = 50A,	$T_J = 25^{\circ}C$	-	11.3	13.4	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 10V		-	25.3	30.0	mΩ
-	c Characteristics						
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 40V, V <sub>GS</sub> = 0V, f = 1MHz		-	1440	-	pF
C <sub>oss</sub>	Output Capacitance			-	300	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	6 ANU-		-	14	-	pF
R <sub>g</sub>	Gate Resistance	f = 1MHz		-	2.0	-	Ω
Q <sub>g(ToT)</sub>	Total Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 64V$		-	20	30	nC
Q <sub>g(th)</sub>	Threshold Gate Charge	V <sub>GS</sub> = 0 to 2	I <sub>D</sub> = 50A	-	2.7	-	nC
Q <sub>gs</sub>	Gate-to-Source Gate Charge		_	-	8.8	-	nC
Q <sub>gd</sub>	Gate-to-Drain "Miller" Charge			-	4.4	-	nC
Switchi	ng Characteristics						
t <sub>on</sub>	Turn-On Time			-	-	31	ns
t <sub>d(on)</sub>	Turn-On Delay		F	-	13	-	ns
t <sub>r</sub>	Rise Time	$V_{DD}$ = 40V, I <sub>D</sub> = 50A, $V_{GS}$ = 10V, R <sub>GEN</sub> = 6 $\Omega$		-	8	-	ns
t <sub>d(off)</sub>	Turn-Off Delay			-	15	-	ns
t <sub>f</sub>	Fall Time		F	-	5	-	ns
t <sub>off</sub>	Turn-Off Time			-	-	30	ns
Drain-S	ource Diode Characteristics						
Van	Source-to-Drain Diode Voltage	I <sub>SD</sub> =50A, V	′ <sub>GS</sub> = 0V	-	-	1.25	V
V <sub>SD</sub>	Source-to-Drain Diode voltage	I <sub>SD</sub> = 25A, \	/ <sub>GS</sub> = 0V	-	-	1.2	V
t <sub>rr</sub>	Reverse-Recovery Time	I <sub>F</sub> = 50A, dI <sub>SD</sub> /dt = 100A/μs V <sub>DD</sub> = 64V		-	37	55	ns
Q <sub>rr</sub>	Reverse-Recovery Charge			-	23	35	nC



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